



## TELUX™ LED

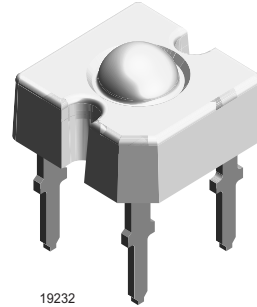
### Description

The TELUX™ series is a clear, non diffused LED for high end applications where supreme luminous flux is required.

It is designed in an industry standard 7.62 mm square package utilizing highly developed (AS) AllnGaP and InGaN technologies.

The supreme heat dissipation of TELUX™ allows applications at high ambient temperatures.

All packing units are binned for luminous flux and color to achieve best homogenous light appearance in application.



### Features

- Utilizing (AS) AllnGaP and InGaN technologies
- High luminous flux
- Supreme heat dissipation:  $R_{thJP}$  is 90 K/W
- High operating temperature:  
 $T_{amb} = - 40 \text{ to } + 110 \text{ }^\circ\text{C}$
- Type TLWR meets SAE and ECE color requirements
- Packed in tubes for automatic insertion
- Luminous flux and color categorized for each tube
- Small mechanical tolerances allow precise usage of external reflectors or lightguides
- TLWR and TLWY types additionally forward voltage categorized
- ESD-withstand voltage:  
> 2 kV acc. to MIL STD 883 D, Method 3015.7 for AllnGaP, > 1 kV for InGaN
- Lead-free device

### Applications

- Exterior lighting
- Dashboard illumination
- Tail-, Stop - and Turn Signals of motor vehicles
- Replaces incandescent lamps
- Traffic signals and signs

### Parts Table

Part	Color, Luminous Intensity	Angle of Half Intensity ( $\pm\phi$ )	Technology
TLWR7600	Red, $\phi_V = (1500 \text{ to } 3000) \text{ mlm}$	30 °	AllnGaP on GaAs
TLWY7600	Yellow, $\phi_V = (1000 \text{ to } 2400) \text{ mlm}$	30 °	AllnGaP on GaAs
TLWO7600	Soft orange, $\phi_V = (1500 \text{ to } 3000) \text{ mlm}$	30 °	AllnGaP on GaAs
TLWTG7600	True green, $\phi_V = (630 \text{ to } 1800) \text{ mlm}$	30 °	InGaN on SiC
TLWBG7600	Blue green, $\phi_V = (400 \text{ to } 1250) \text{ mlm}$	30 °	InGaN on SiC
TLWB7600	Blue, $\phi_V = (200 \text{ to } 630) \text{ mlm}$	30 °	InGaN on SiC
TLWW7600	White, $\phi_V = (200 \text{ to } 630) \text{ mlm}$	30 °	InGaN / TAG on SiC

### Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

TLWR7600, TLWY7600, TLWO7600

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage	$I_R = 10\ \mu\text{A}$	$V_R$	10	V
DC Forward current	$T_{amb} \leq 85\text{ }^{\circ}\text{C}$	$I_F$	70	mA
Surge forward current	$t_p \leq 10\ \mu\text{s}$	$I_{FSM}$	1	A
Power dissipation	$T_{amb} \leq 85\text{ }^{\circ}\text{C}$	$P_V$	187	mW
Junction temperature		$T_j$	125	$^{\circ}\text{C}$
Operating temperature range		$T_{amb}$	- 40 to + 110	$^{\circ}\text{C}$
Storage temperature range		$T_{stg}$	- 55 to + 110	$^{\circ}\text{C}$
Soldering temperature	$t \leq 5\ \text{s}$ , 1.5 mm from body preheat temperature 100 $^{\circ}\text{C}$ / 30 sec.	$T_{sd}$	260	$^{\circ}\text{C}$
Thermal resistance junction/ ambient	with cathode heatsink of 70 mm <sup>2</sup>	$R_{thJA}$	200	K/W
Thermal resistance junction/pin		$R_{thJP}$	90	K/W

TLWTG7600, TLWBG7600, TLWB7600, TLWW7600

Parameter	Test condition	Part	Symbol	Value	Unit
Reverse voltage	$I_R = 10\ \mu\text{A}$		$V_R$	5	V
DC Forward current	$T_{amb} \leq 50\text{ }^{\circ}\text{C}$		$I_F$	50	mA
Surge forward current	$t_p \leq 10\ \mu\text{s}$		$I_{FSM}$	0.1	A
Power dissipation	$T_{amb} \leq 50\text{ }^{\circ}\text{C}$	TLWTG7600	$P_V$	230	mW
		TLWBG7600	$P_V$	230	mW
		TLWB7600	$P_V$	230	mW
		TLWW7600	$P_V$	255	mW
Junction temperature			$T_j$	100	$^{\circ}\text{C}$
Operating temperature range			$T_{amb}$	- 40 to + 100	$^{\circ}\text{C}$
Storage temperature range			$T_{stg}$	- 55 to + 100	$^{\circ}\text{C}$
Soldering temperature	$t \leq 5\ \text{s}$ , 1.5 mm from body preheat temperature 100 $^{\circ}\text{C}$ / 30 sec.		$T_{sd}$	260	$^{\circ}\text{C}$
Thermal resistance junction/ ambient	with cathode heatsink of 70 mm <sup>2</sup>		$R_{thJA}$	200	K/W
Thermal resistance junction/pin			$R_{thJP}$	90	K/W

### Optical and Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

#### Red

TLWR7600

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Total flux	$I_F = 70\ \text{mA}$ , $R_{thJA} = 200\text{ }^{\circ}\text{K/W}$	$\phi_V$	1500	2100	3000	mlm
Luminous intensity/Total flux	$I_F = 70\ \text{mA}$ , $R_{thJA} = 200\text{ }^{\circ}\text{K/W}$	$I_V/\phi_V$		0.8		mcd/mlm
Dominant wavelength	$I_F = 70\ \text{mA}$ , $R_{thJA} = 200\text{ }^{\circ}\text{K/W}$	$\lambda_d$	611	618	634	nm
Peak wavelength	$I_F = 70\ \text{mA}$ , $R_{thJA} = 200\text{ }^{\circ}\text{K/W}$	$\lambda_p$		624		nm
Angle of half intensity	$I_F = 70\ \text{mA}$ , $R_{thJA} = 200\text{ }^{\circ}\text{K/W}$	$\phi$		$\pm 30$		deg
Total included angle	90 % of Total Flux Captured	$\phi$		75		deg
Forward voltage	$I_F = 70\ \text{mA}$ , $R_{thJA} = 200\text{ }^{\circ}\text{K/W}$	$V_F$	1.83	2.2	2.67	V



Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Reverse voltage	$I_R = 10 \mu\text{A}$	$V_R$	10	20		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$	$C_j$		17		pF
Temperature coefficient of $\lambda_{\text{dom}}$	$I_F = 50 \text{ mA}$	$TC\lambda_{\text{dom}}$		0.05		nm/K

### Soft Orange

#### TLWO7600

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Total flux	$I_F = 70 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$\phi_V$	1500	2100	3000	mlm
Luminous intensity/Total flux	$I_F = 70 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$I_V/\phi_V$		0.8		mcd/mlm
Dominant wavelength	$I_F = 70 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$\lambda_d$	598	605	611	nm
Peak wavelength	$I_F = 70 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$\lambda_p$		610		nm
Angle of half intensity	$I_F = 70 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$\varphi$		$\pm 30$		deg
Total included angle	90 % of Total Flux Captured	$\varphi$		75		deg
Forward voltage	$I_F = 70 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$V_F$	1.83	2.2	2.67	V
Reverse voltage	$I_R = 10 \mu\text{A}$	$V_R$	10	20		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$	$C_j$		17		pF
Temperature coefficient of $\lambda_{\text{dom}}$	$I_F = 50 \text{ mA}$	$TC\lambda_{\text{dom}}$		0.06		nm/K

### Yellow

#### TLWY7600

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Total flux	$I_F = 70 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$\phi_V$	1000	1400	2400	mlm
Luminous intensity/Total flux	$I_F = 70 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$I_V/\phi_V$		0.8		mcd/mlm
Dominant wavelength	$I_F = 70 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$\lambda_d$	585	592	597	nm
Peak wavelength	$I_F = 70 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$\lambda_p$		594		nm
Angle of half intensity	$I_F = 70 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$\varphi$		$\pm 30$		deg
Total included angle	90 % of Total Flux Captured	$\varphi$		75		deg
Forward voltage	$I_F = 70 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$V_F$	1.83	2.1	2.67	V
Reverse voltage	$I_R = 10 \mu\text{A}$	$V_R$	10	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$	$C_j$		32		pF
Temperature coefficient of $\lambda_{\text{dom}}$	$I_F = 50 \text{ mA}$	$TC\lambda_{\text{dom}}$		0.1		nm/K

### True green

#### TLWTG7600

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Total flux	$I_F = 50 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$\phi_V$	630	900	1800	mlm
Luminous intensity/Total flux	$I_F = 50 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$I_V/\phi_V$		0.8		mcd/mlm
Dominant wavelength	$I_F = 50 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$\lambda_d$	509	523	535	nm
Peak wavelength	$I_F = 50 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$\lambda_p$		518		nm
Angle of half intensity	$I_F = 50 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$\varphi$		$\pm 30$		deg
Total included angle	90 % of Total Flux Captured	$\varphi$		75		deg
Forward voltage	$I_F = 50 \text{ mA}, R_{\text{thJA}} = 200 \text{ }^\circ\text{K/W}$	$V_F$		4.2	4.7	V
Reverse voltage	$I_R = 10 \mu\text{A}$	$V_R$	5	10		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$	$C_j$		50		pF
Temperature coefficient of $\lambda_{\text{dom}}$	$I_F = 30 \text{ mA}$	$TC\lambda_{\text{dom}}$		0.02		nm/K

### Blue green

#### TLWBG7600

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Total flux	$I_F = 50 \text{ mA}$ , $R_{thJA} = 200 \text{ }^\circ\text{K/W}$	$\phi_V$	400	700	1250	mlm
Luminous intensity/Total flux	$I_F = 50 \text{ mA}$ , $R_{thJA} = 200 \text{ }^\circ\text{K/W}$	$I_V/\phi_V$		0.8		mcd/mlm
Dominant wavelength	$I_F = 50 \text{ mA}$ , $R_{thJA} = 200 \text{ }^\circ\text{K/W}$	$\lambda_d$	492	505	510	nm
Peak wavelength	$I_F = 50 \text{ mA}$ , $R_{thJA} = 200 \text{ }^\circ\text{K/W}$	$\lambda_p$		503		nm
Angle of half intensity	$I_F = 50 \text{ mA}$ , $R_{thJA} = 200 \text{ }^\circ\text{K/W}$	$\phi$		$\pm 30$		deg
Total included angle	90 % of Total Flux Captured	$\phi$		75		deg
Forward voltage	$I_F = 50 \text{ mA}$ , $R_{thJA} = 200 \text{ }^\circ\text{K/W}$	$V_F$		4.2	4.7	V
Reverse voltage	$I_R = 10 \text{ }\mu\text{A}$	$V_R$	5	10		V
Junction capacitance	$V_R = 0$ , $f = 1 \text{ MHz}$	$C_j$		50		pF
Temperature coefficient of $\lambda_{dom}$	$I_F = 30 \text{ mA}$	$TC\lambda_{dom}$		0.02		nm/K

### Blue

#### TLWB7600

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Total flux	$I_F = 50 \text{ mA}$ , $R_{thJA} = 200 \text{ }^\circ\text{K/W}$	$\phi_V$	200	330	630	mlm
Luminous intensity/Total flux	$I_F = 50 \text{ mA}$ , $R_{thJA} = 200 \text{ }^\circ\text{K/W}$	$I_V/\phi_V$		0.8		mcd/mlm
Dominant wavelength	$I_F = 50 \text{ mA}$ , $R_{thJA} = 200 \text{ }^\circ\text{K/W}$	$\lambda_d$	462	470	476	nm
Peak wavelength	$I_F = 50 \text{ mA}$ , $R_{thJA} = 200 \text{ }^\circ\text{K/W}$	$\lambda_p$		460		nm
Angle of half intensity	$I_F = 50 \text{ mA}$ , $R_{thJA} = 200 \text{ }^\circ\text{K/W}$	$\phi$		$\pm 30$		deg
Total included angle	90 % of Total Flux Captured	$\phi$		75		deg
Forward voltage	$I_F = 50 \text{ mA}$ , $R_{thJA} = 200 \text{ }^\circ\text{K/W}$	$V_F$		4.3	4.7	V
Reverse voltage	$I_R = 10 \text{ }\mu\text{A}$	$V_R$	5	10		V
Junction capacitance	$V_R = 0$ , $f = 1 \text{ MHz}$	$C_j$		50		pF
Temperature coefficient of $\lambda_{dom}$	$I_F = 30 \text{ mA}$	$TC\lambda_{dom}$		0.03		nm/K

### White

#### TLWW7600

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Total flux	$I_F = 50 \text{ mA}$ , $R_{thJA} = 200 \text{ }^\circ\text{K/W}$	$\phi_V$	400	650	1250	mlm
Luminous intensity/Total flux	$I_F = 50 \text{ mA}$ , $R_{thJA} = 200 \text{ }^\circ\text{K/W}$	$I_V/\phi_V$		0.8		mcd/mlm
Color temperature	$I_F = 50 \text{ mA}$ , $R_{thJA} = 200 \text{ }^\circ\text{K/W}$	$T_K$		5500		K
Angle of half intensity	$I_F = 50 \text{ mA}$ , $R_{thJA} = 200 \text{ }^\circ\text{K/W}$	$\phi$		$\pm 30$		deg
Total included angle	90 % of Total Flux Captured	$\phi$		75		deg
Forward voltage	$I_F = 50 \text{ mA}$ , $R_{thJA} = 200 \text{ }^\circ\text{K/W}$	$V_F$		4.3	5.1	V
Reverse voltage	$I_R = 10 \text{ }\mu\text{A}$	$V_R$	5	10		V
Junction capacitance	$V_R = 0$ , $f = 1 \text{ MHz}$	$C_j$		50		pF

## Typical Characteristics ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

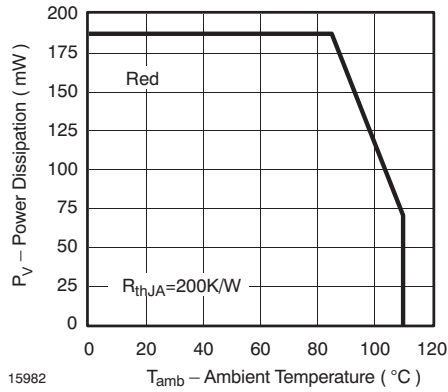


Figure 1. Power Dissipation vs. Ambient Temperature

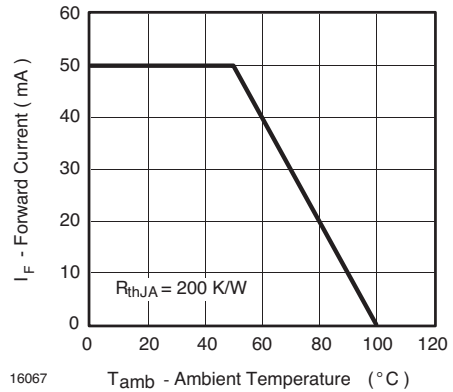


Figure 4. Forward Current vs. Ambient Temperature for InGaN

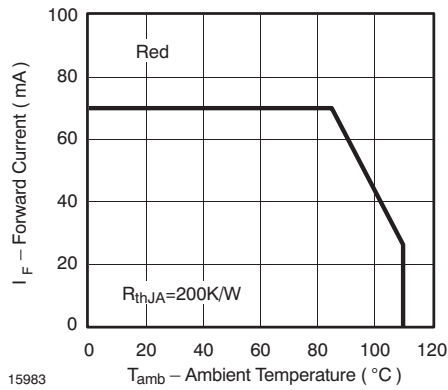


Figure 2. Forward Current vs. Ambient Temperature

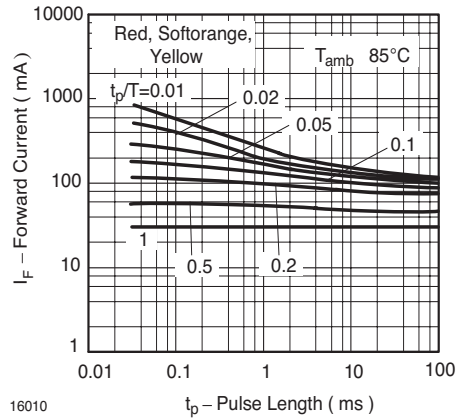


Figure 5. Forward Current vs. Pulse Length

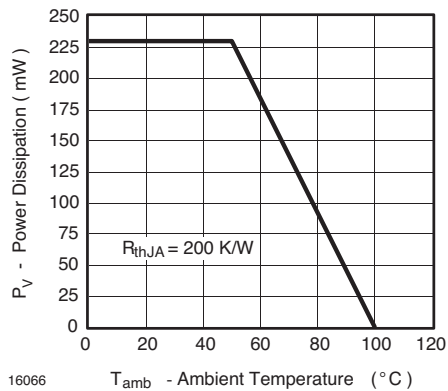


Figure 3. Power Dissipation vs. Ambient Temperature for InGaN

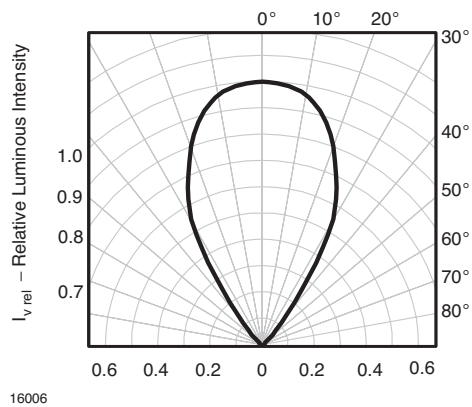


Figure 6. Rel. Luminous Intensity vs. Angular Displacement for 60° emission angle

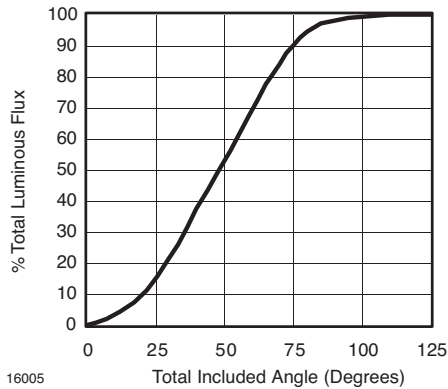


Figure 7. Percentage Total Luminous Flux vs. Total Included Angle for 60° emission angle

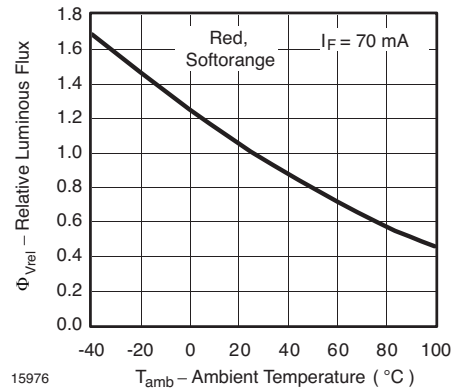


Figure 10. Rel. Luminous Flux vs. Ambient Temperature

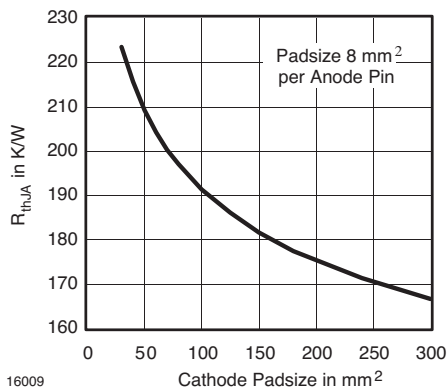


Figure 8. Thermal Resistance Junction Ambient vs. Cathode Padsize

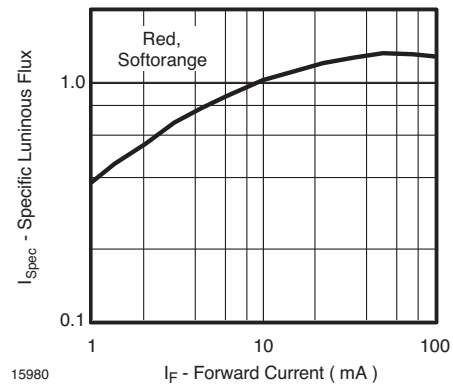


Figure 11. Specific Luminous Flux vs. Forward Current

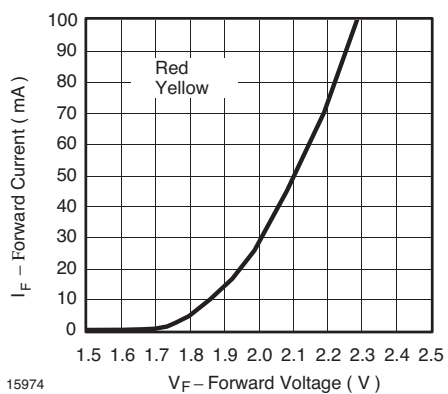


Figure 9. Forward Current vs. Forward Voltage

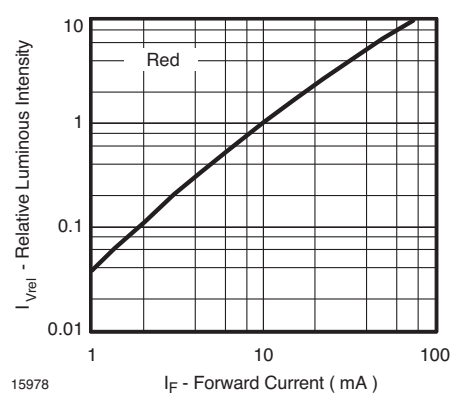


Figure 12. Relative Luminous Flux vs. Forward Current

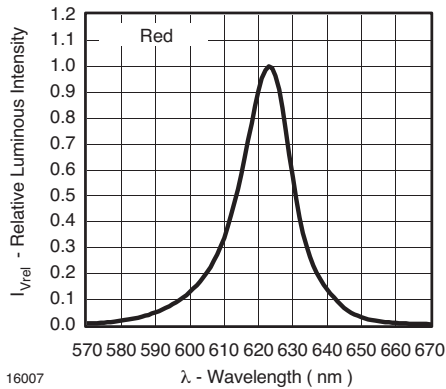


Figure 13. Relative Intensity vs. Wavelength

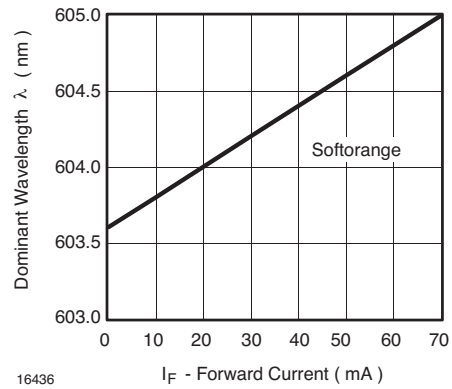


Figure 16. Dominant Wavelength vs. Forward Current

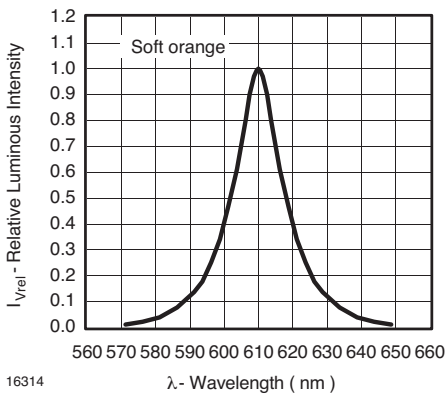


Figure 14. Relative Intensity vs. Wavelength

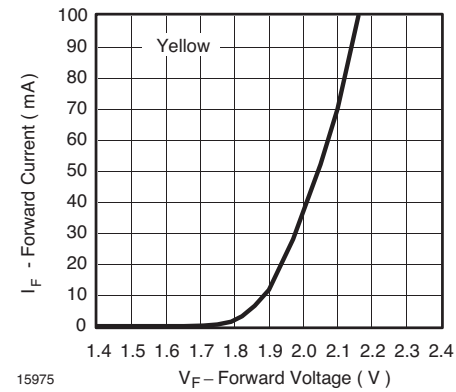


Figure 17. Forward Current vs. Forward Voltage

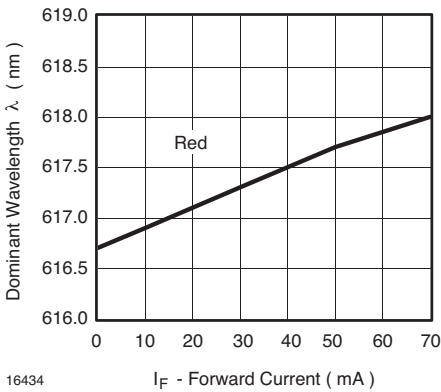


Figure 15. Dominant Wavelength vs. Forward Current

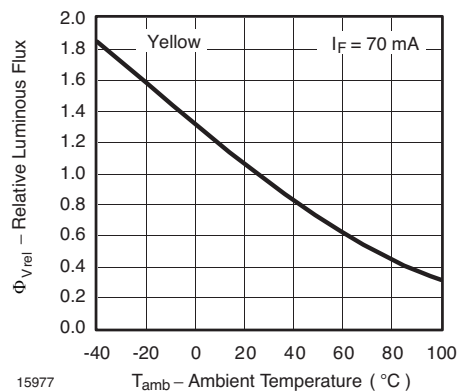
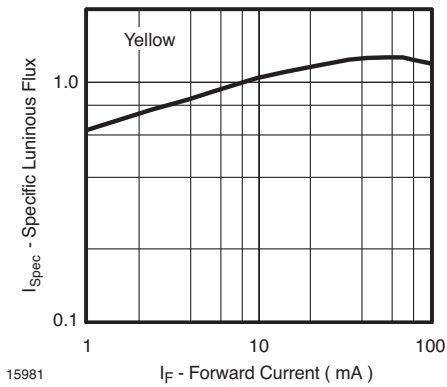
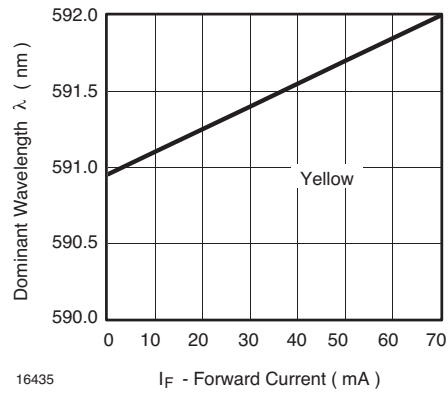


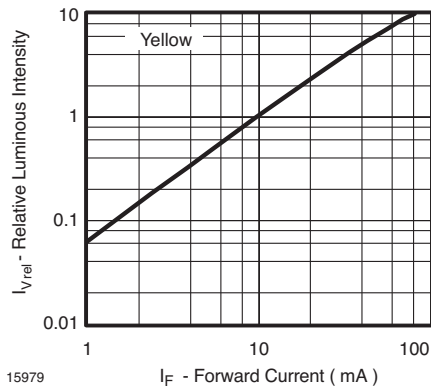
Figure 18. Rel. Luminous Flux vs. Ambient Temperature



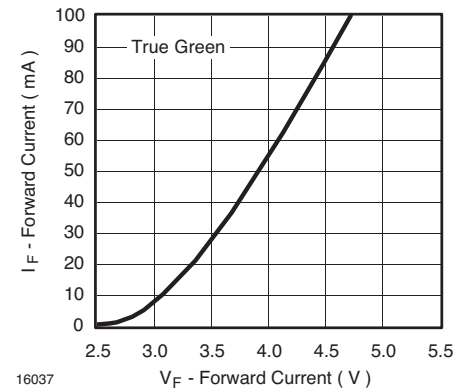
15981  
Figure 19. Specific Luminous Flux vs. Forward Current



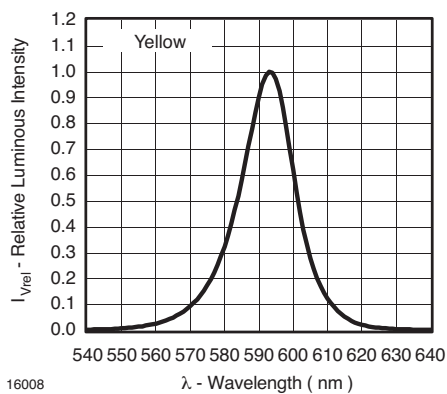
16435  
Figure 22. Dominant Wavelength vs. Forward Current



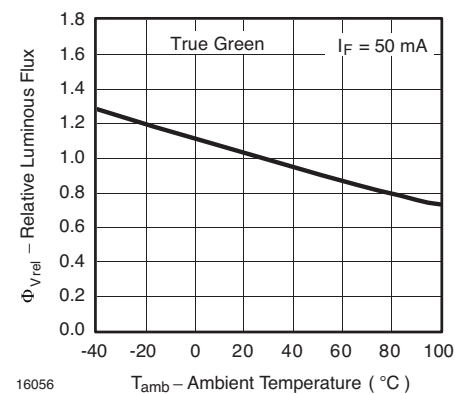
15979  
Figure 20. Relative Luminous Flux vs. Forward Current



16037  
Figure 23. Forward Current vs. Forward Voltage



16008  
Figure 21. Relative Intensity vs. Wavelength



16056  
Figure 24. Rel. Luminous Flux vs. Ambient Temperature



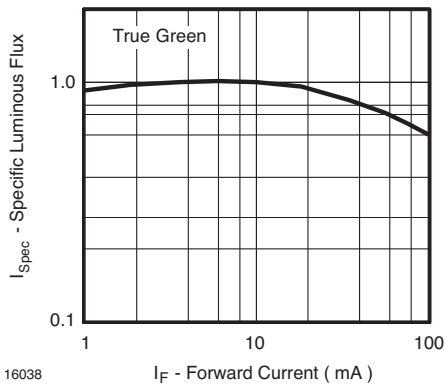


Figure 25. Specific Luminous Flux vs. Forward Current

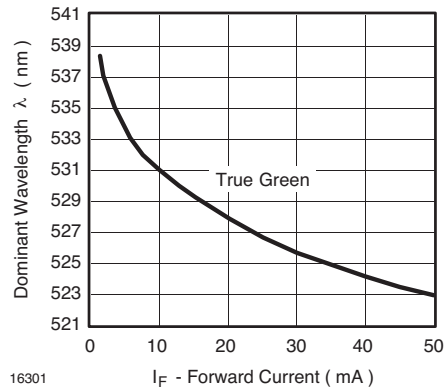


Figure 28. Dominant Wavelength vs. Forward Current

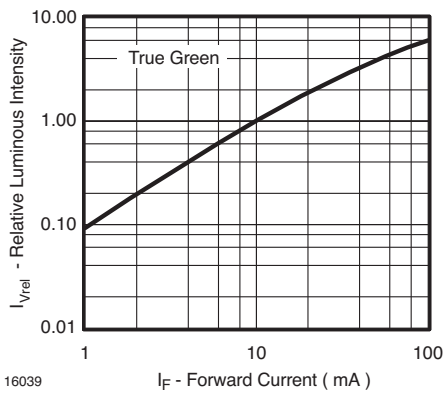


Figure 26. Relative Luminous Flux vs. Forward Current

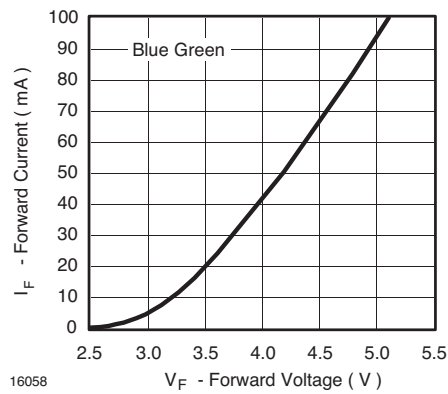


Figure 29. Forward Current vs. Forward Voltage

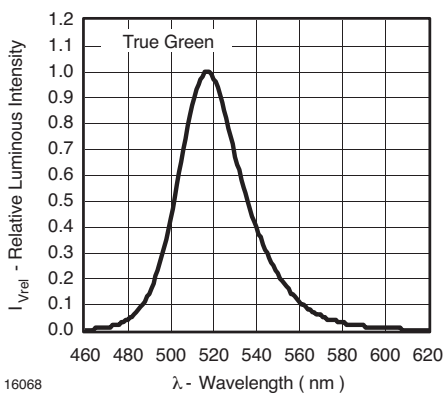


Figure 27. Relative Intensity vs. Wavelength

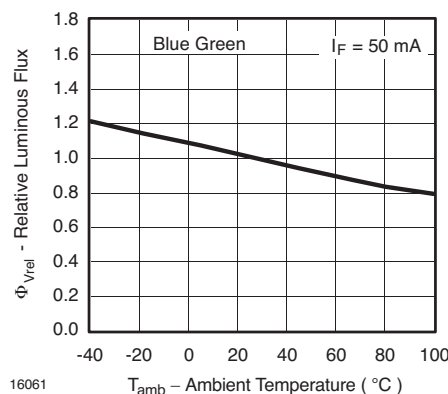


Figure 30. Rel. Luminous Flux vs. Ambient Temperature

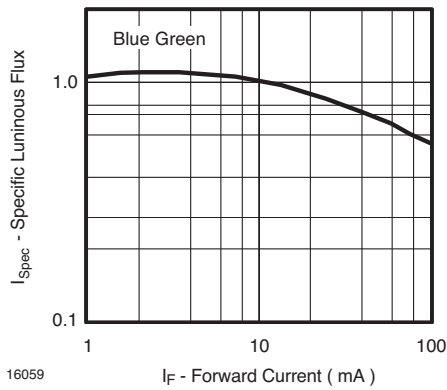


Figure 31. Specific Luminous Flux vs. Forward Current

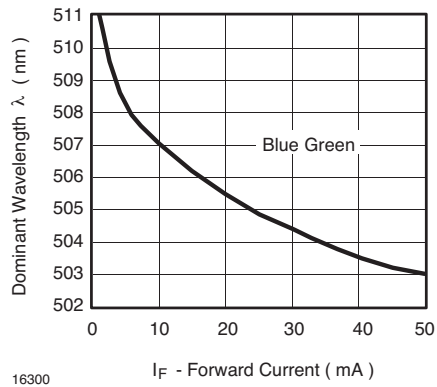


Figure 34. Dominant Wavelength vs. Forward Current

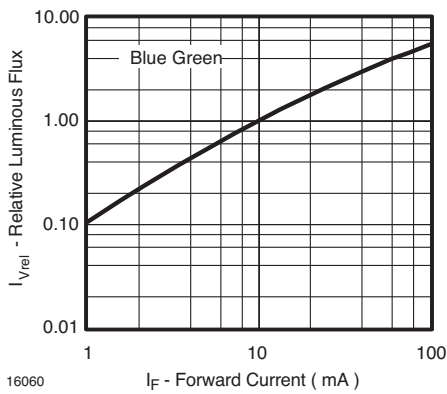


Figure 32. Relative Luminous Flux vs. Forward Current

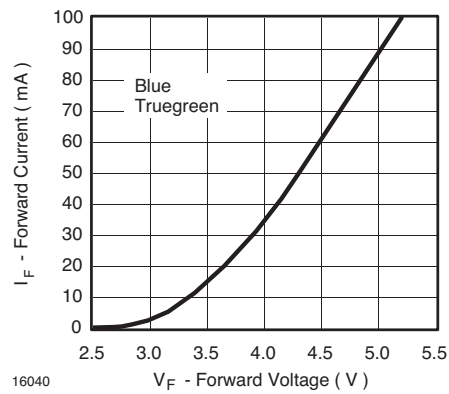


Figure 35. Forward Current vs. Forward Voltage

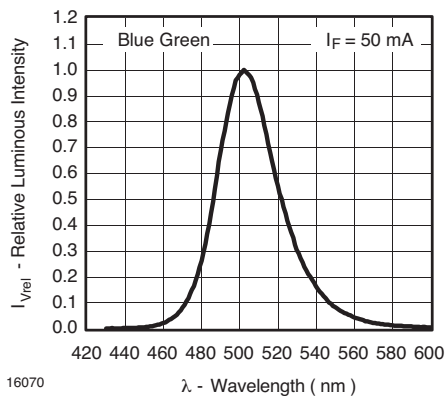


Figure 33. Relative Intensity vs. Wavelength

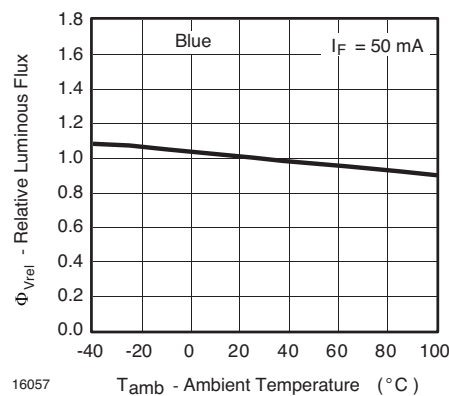


Figure 36. Rel. Luminous Flux vs. Ambient Temperature

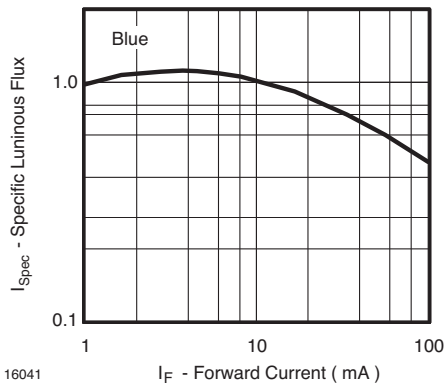


Figure 37. Specific Luminous Flux vs. Forward Current

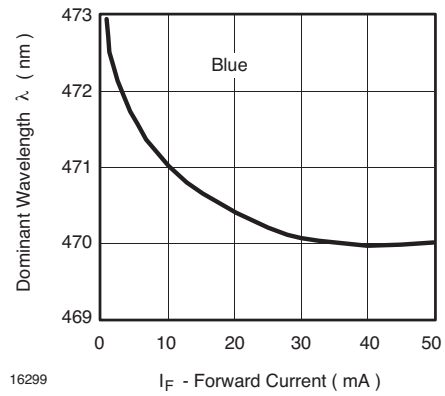


Figure 40. Dominant Wavelength vs. Forward Current

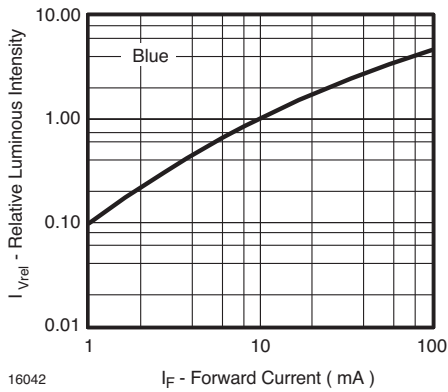


Figure 38. Relative Luminous Flux vs. Forward Current

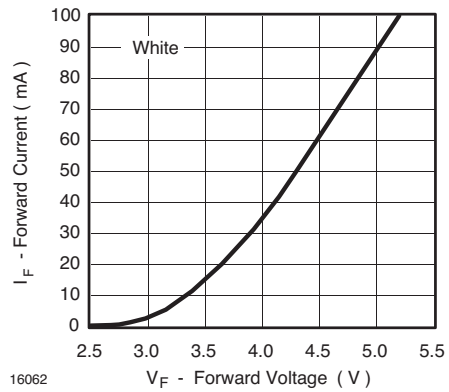


Figure 41. Forward Current vs. Forward Voltage

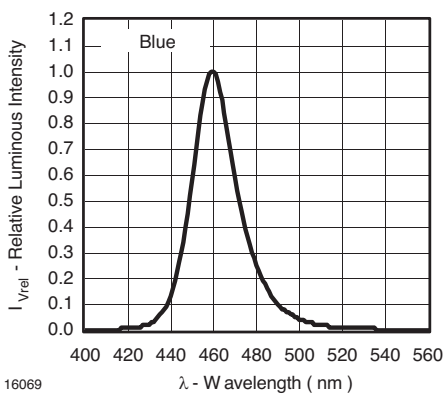


Figure 39. Relative Intensity vs. Wavelength

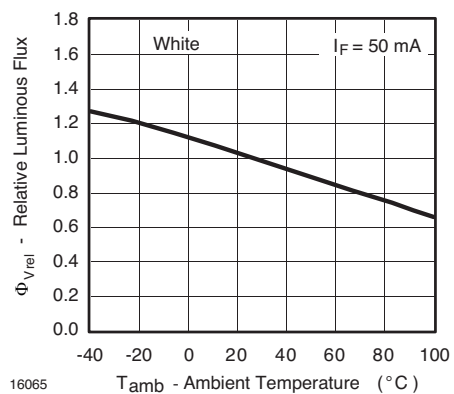


Figure 42. Rel. Luminous Flux vs. Ambient Temperature

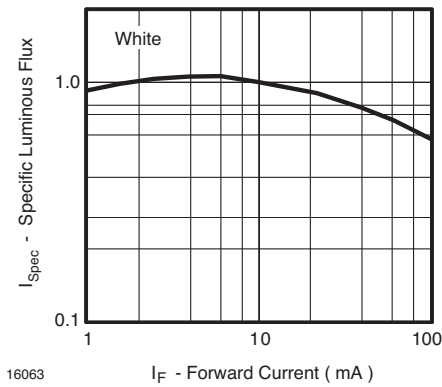


Figure 43. Specific Luminous Flux vs. Forward Current

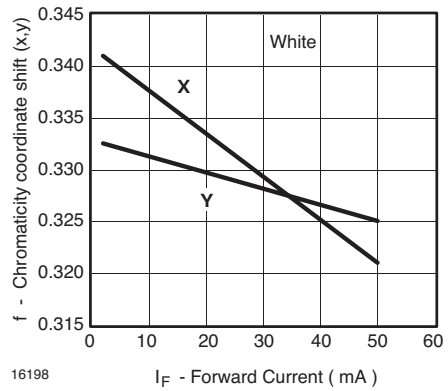


Figure 46. Chromaticity Coordinate Shift vs. Forward Current

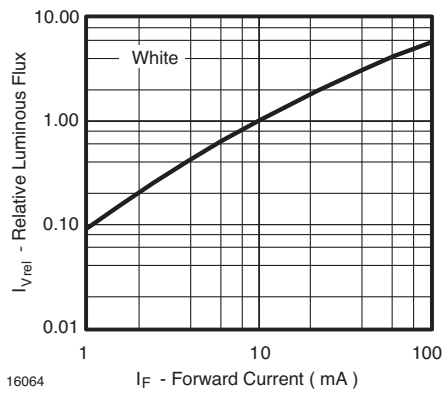


Figure 44. Relative Luminous Flux vs. Forward Current

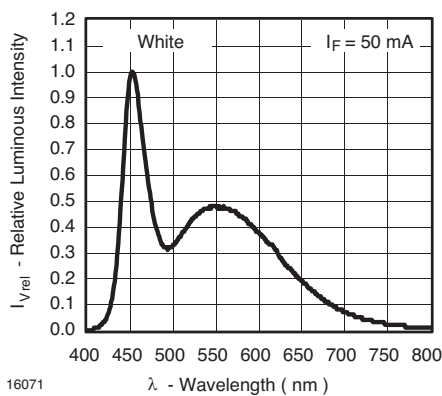
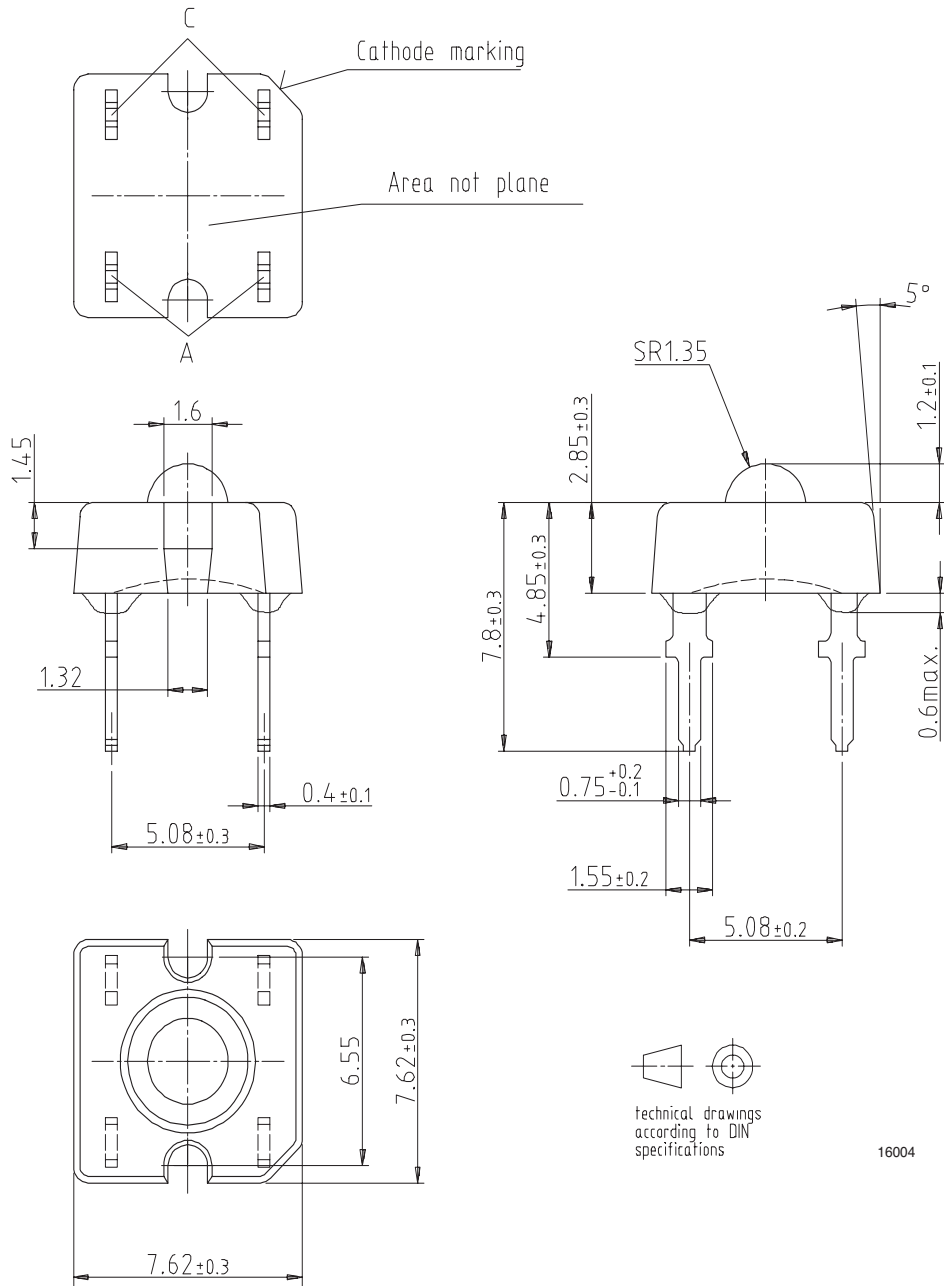


Figure 45. Relative Intensity vs. Wavelength

## Package Dimensions in mm



### Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design  
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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